

Current Regulator Diode



Linear Systems replaces discontinued Siliconix J503

The Linear Systems J503 is a ± 20% range current regulator

The J503 is a ±20% range current regulator designed for demanding applications in test equipment and instrumentation. The J503 utilizes JFET techniques to produce a single two-leaded device which is extremely simple to operate.

- Two-Lead Plastic Package
- Guaranteed ±20% Tolerance
- Operation up to 50V
- **Excellent Temperature Stability**
- Simple Series Circuitry, No Separate Voltage Source
- Tight Guaranteed Circuit Performance
- Excellent Performance in Low-Voltage/Battery Circuits and High-Voltage Spike Protection
- High Circuit Stability vs. Temperature

J503 Applications:

- Constant-Current Supply
- Current-Limiting
- **Timing Circuits**

FEATURES						
REPLACEMENT SOURCE FOR SILICONIX J503						
WIDE CURRENT RANGE	0.56mA ± 20%					
BIASING NOT REQUIRED V _{GS} = 0						
ABSOLUTE MAXIMUM RATINGS ¹						
@ 25 °C (unless otherwise stated)						
Maximum Temperatures						
Storage Temperature	-55 to 150°C					
Junction Operating Temperature	-55 to 135°C					
Maximum Power Dissipation						
Continuous Power Dissipation @125°C	360mW					
Maximum Currents						
Forward Current	20mA					
Reverse Current	50mA					
Maximum Voltages						
Peak Operating Voltage	P _{OV} = 50V					
4.4. D						

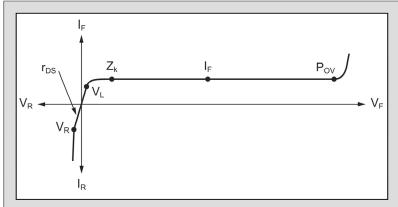
ELECTRICAL CHARACTERISTICS @ 25 °C (unless otherwise stated)

SYMBOL	CHARACTERISTIC	MIN	TYP	MAX	UNITS	CONDITIONS
Pov	Peak Operating Voltage ²	50			V	$I_{F} = 1.1I_{F(max)}$
V_R	Reverse Voltage		8.0		٧	$I_R = 1mA$
C _F	Forward Capacitance		2.2		pF	$V_F = 25V, f = 1MHz$

SPECIFIC ELECTRICAL CHARACTERISTICS @ 25 °C (unless otherwise stated)

PART	Fe	orward Currer I _F	nt ³	Dynamic Ir Z	, - -	Knee Impedance Z _k Limiting		Voltage⁵ ⁄∟
		V _F = 25V			V _F = 25V		$I_F = 0.8I_{F(min)}$	
	MIN	NOM	MAX	MIN	TYP	TYP	TYP	MAX
J503	0.448	0.56	0.672	1.20	5	0.80	1.7	0.7

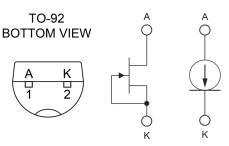
V-I CHARACTERISTICS CURRENT REGULATING DIODE



- 1. Absolute maximum ratings are limiting values above which serviceability may be impaired. 2. Pulsed, t = 2ms. Maximum V_F where $IF < 1.1_{IF}(max)$.
- 3. Pulsed, t = 2ms. Continuous currents may vary
- 4. Pulsed, t = 2ms. Continuous impedances may vary. 5. Min V_F required to ensure $I_F = 0.8_{IF}$ (min).

Available Packages:

TO-92 Bare Die.



Please contact Micross for full package and die dimensions

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